



US 20190058153A1

(19) **United States**(12) **Patent Application Publication**
LUO(10) **Pub. No.: US 2019/0058153 A1**(43) **Pub. Date: Feb. 21, 2019**(54) **PACKAGE SUBSTRATE, MANUFACTURING METHOD THEREOF, OLED DISPLAY PANEL AND MANUFACTURING METHOD THEREOF**(71) Applicant: **BOE TECHNOLOGY GROUP CO., LTD.**, Beijing (CN)(72) Inventor: **Chengyuan LUO**, Beijing (CN)(73) Assignee: **BOE TECHNOLOGY GROUP CO., LTD.**, Beijing (CN)(21) Appl. No.: **15/974,903**(22) Filed: **May 9, 2018**(30) **Foreign Application Priority Data**

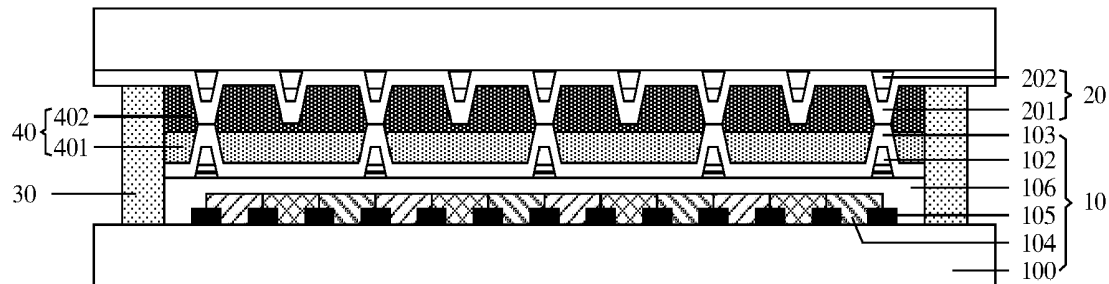
Aug. 16, 2017 (CN) 201710701692.6

Publication Classification(51) **Int. Cl.****H01L 51/52** (2006.01)**H01L 27/32** (2006.01)**H01L 51/56** (2006.01)(52) **U.S. Cl.**CPC **H01L 51/5246** (2013.01); **H01L 27/3246** (2013.01); **H01L 2251/5315** (2013.01); **H01L 51/56** (2013.01); **H01L 27/322** (2013.01); **H01L 51/5203** (2013.01)

(57)

ABSTRACT

A package substrate, a manufacturing method thereof, an organic light-emitting diode (OLED) display panel and a manufacturing method thereof are provided. The package substrate includes a transparent substrate; a plurality of spacers disposed on the transparent substrate; and auxiliary electrodes provided on the spacers and in a non-light-emitting region. Orthographic projections of the spacers on an array substrate fall within orthographic areas of a pixel define layer (PDL) on the array substrate.



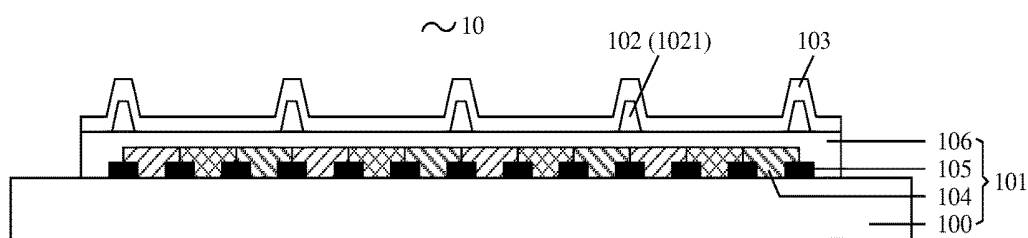


FIG. 1

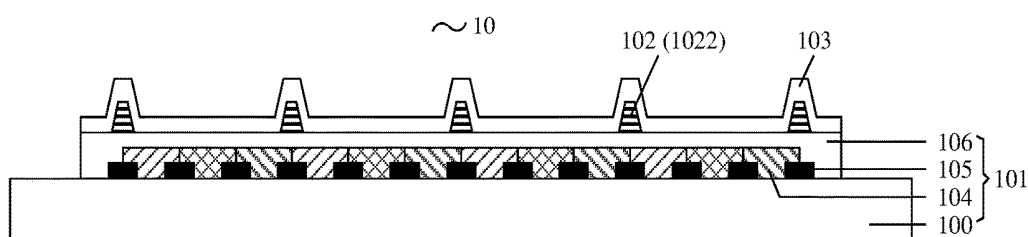


FIG. 2

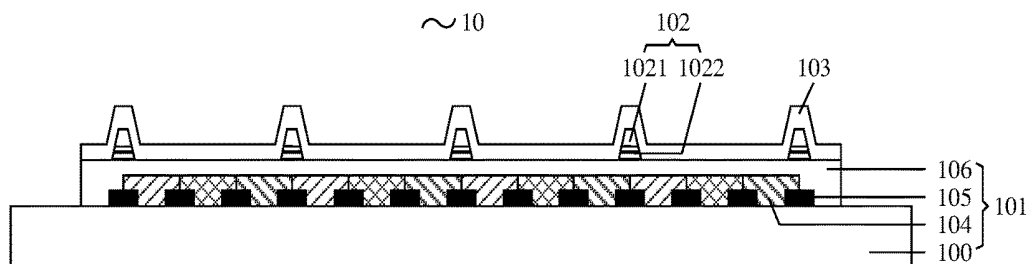


FIG. 3

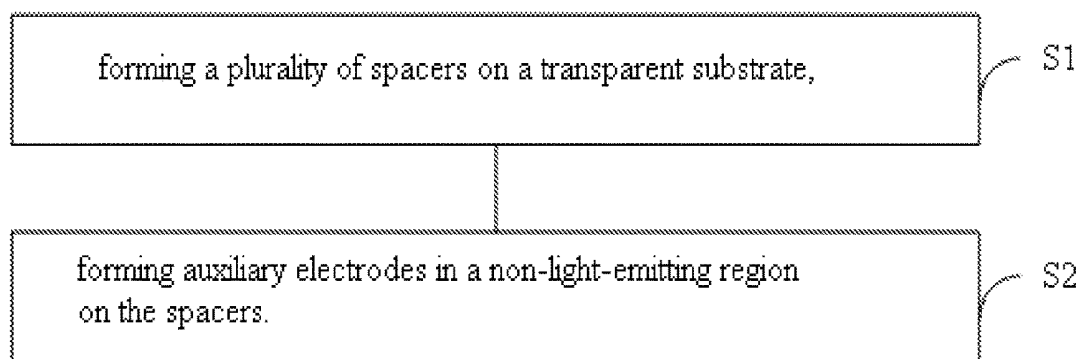


FIG. 4

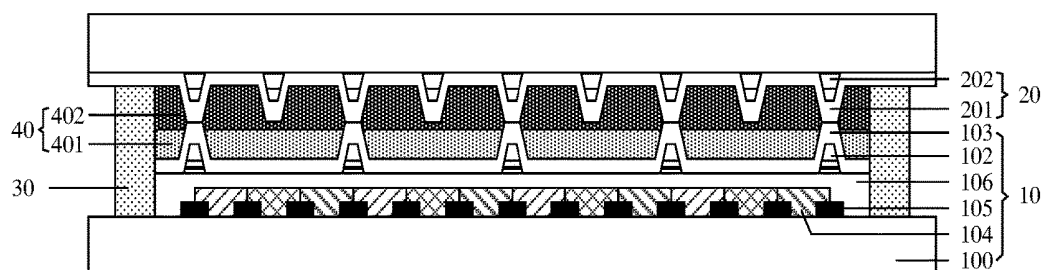


FIG. 5

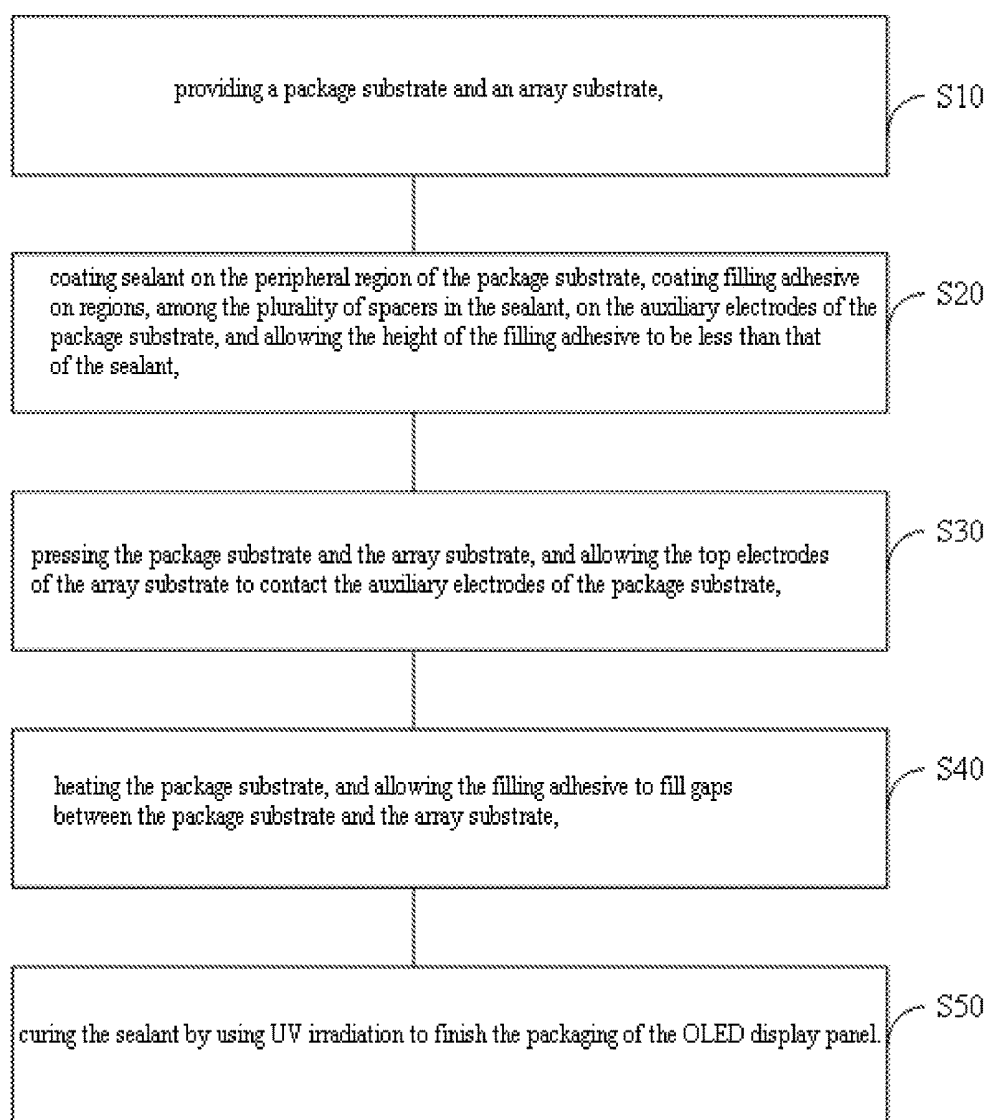


FIG. 6

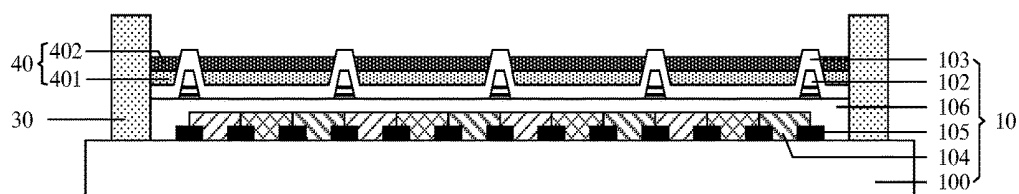


FIG. 7

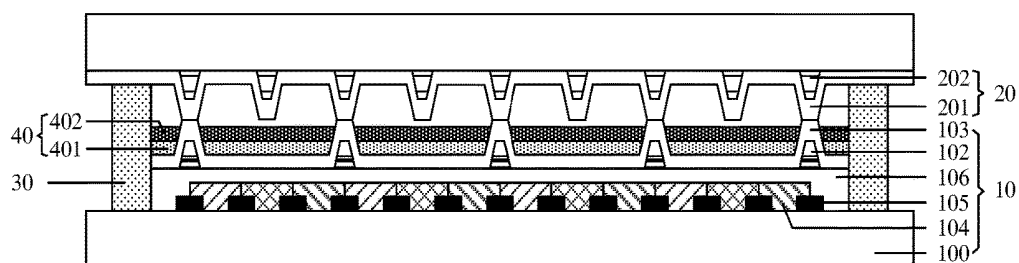


FIG. 8

**PACKAGE SUBSTRATE, MANUFACTURING
METHOD THEREOF, OLED DISPLAY PANEL
AND MANUFACTURING METHOD
THEREOF**

**CROSS REFERENCE TO RELATED
APPLICATIONS**

[0001] The application claims priority to the Chinese patent application No. 201710701692.6, filed Aug. 16, 2017 on SIPO, titled “Package Substrate, Manufacturing Method thereof, OLED Display Panel and Manufacturing Method thereof”, which is incorporated herein by reference in its entirety.

TECHNICAL FIELD

[0002] Embodiments of the present disclosure relate to a package substrate, a manufacturing method thereof, an organic light-emitting diode (OLED) display panel and a manufacturing method thereof.

BACKGROUND

[0003] OLED, taken as a current mode luminescent device, is widely applied in high-performance display field due to the advantages of autoluminescence, rapid response, high contrast, wide viewing angle, and capability of being manufactured on a flexible substrate. Top-emission type OLED device has become the main research direction of OLED devices due to the advantages of high aperture opening ratio and capability of utilizing microcavity effect to realize light extraction optimization.

SUMMARY

[0004] Embodiments of the present disclosure provide a package substrate, a manufacturing method thereof, an organic light-emitting diode (OLED) display panel and a manufacturing method thereof.

[0005] At least one embodiment of the present disclosure provides a package substrate, arranged oppositely to an array substrate, comprising: a transparent substrate; a plurality of spacers provided on the transparent substrate; and auxiliary electrodes provided on the spacers and in a non-light-emitting region. Orthographic projections of the plurality of spacers on the array substrate fall within orthographic areas of a pixel define layer (PDL) on the array substrate.

[0006] In an example of the present disclosure, the plurality of spacers are post spacers; or the plurality of spacers are conductive poles.

[0007] In an example of the present disclosure, the spacers include post spacers and conductive poles which are directly opposite to each other in position and overlap with each other.

[0008] In an example of the present disclosure, material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and indium tin oxide (ITO); and material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

[0009] In an example of the present disclosure, the transparent substrate is a base substrate provided with black matrixes (BMs), a color filter (CF) layer and a planarization layer; the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and orthographic

projections of the spacers on the base substrate fall within orthographic projections of the BMs on the base substrate.

[0010] In an example of the present disclosure, the material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and ITO; and the material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

[0011] In an example of the present disclosure, the transparent substrate is a base substrate provided with BMs, a CF layer and a planarization layer; the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and orthographic projections of the spacers on the base substrate fall within orthographic projections of the BMs on the base substrate.

[0012] At least one embodiment of the present disclosure also provides a method for manufacturing the package substrate, wherein the package substrate and the array substrate are oppositely arranged; and the method comprises: forming a plurality of spacers on the transparent substrate; and forming the auxiliary electrodes in a non-light-emitting region on the spacers, wherein orthographic projections of the spacers on the array substrate fall within orthographic areas of the PDL on the array substrate.

[0013] In an example of the present disclosure: forming post spacers on the transparent substrate; or forming conductive poles on the transparent substrate.

[0014] In an example of the present disclosure, forming post spacers and conductive poles, which are directly opposite to and overlap with each other, on the transparent substrate.

[0015] In an example of the present disclosure, the material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and Indium Tin Oxide (ITO); and the material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

[0016] In an example of the present disclosure, the transparent substrate is a base substrate provided with BMs, a CF layer and a planarization layer; the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and orthographic projections of the spacers on the base substrate fall within orthographic areas of the BMs on the base substrate.

[0017] At least one embodiment of the present disclosure also provides an organic light-emitting diode (OLED) display panel, comprising the package substrate, an array substrate, and sealant and filling adhesive between the package substrate and the array substrate. Top electrodes of the array substrate contact the auxiliary electrodes of the package substrate; and the filling adhesive is filled into gaps between the package substrate and the array substrate.

[0018] In an example of the present disclosure, the filling adhesive includes first filling adhesive close to a side of the package substrate and second filling adhesive close to a side of the array substrate facing the side of the package substrate; the first filling adhesive includes thermal expansion materials; the second filling adhesive includes UV curing materials; and the first filling adhesive and the second filling adhesive have different viscosities.

[0019] At least one embodiment of the present disclosure also provides a method for manufacturing an OLED display panel, comprising: providing the package substrate according to claim 1 and an array substrate; applying sealant on the

periphery of the package substrate, applying filling adhesive on regions, among the plurality of spacers in the sealant, on the auxiliary electrodes of the package substrate, and allowing the height of the filling adhesive to be less than the height of the sealant; pressing the package substrate and the array substrate, to allow top electrodes of the array substrate to contact the auxiliary electrodes of the package substrate; and heating the package substrate, to allow filling adhesive to fill into gaps between the package substrate and the array substrate.

[0020] In an example of the present disclosure, the heating of the package substrate to allow the filling adhesive to fill into the gaps between the package substrate and the array substrate comprises: heating the package substrate, allowing the first filling adhesive close to a side of the package substrate to be expanded, and pushing the second filling adhesive close to a side of the array substrate to fill the gaps between the package substrate and the array substrate.

BRIEF DESCRIPTION OF THE DRAWINGS

[0021] Embodiments of the present disclosure will be described in more detail below with reference to accompanying drawings to allow an ordinary skill in the art to more clearly understand embodiments of the present disclosure, in which:

[0022] FIG. 1 is a schematically structural view 1 of the package substrate provided by an exemplary embodiment of the present disclosure;

[0023] FIG. 2 is a schematically structural view 2 of the package substrate provided by an exemplary embodiment of the present disclosure;

[0024] FIG. 3 is a schematically structural view 3 of the package substrate provided by an exemplary embodiment of the present disclosure;

[0025] FIG. 4 is a flow chart of a manufacturing method of the package substrate provided by an exemplary embodiment of the present disclosure;

[0026] FIG. 5 is a schematically structural view of an OLED display panel provided by an exemplary embodiment of the present disclosure;

[0027] FIG. 6 is a flow chart of a manufacturing method of the OLED display panel provided by an exemplary embodiment of the present disclosure; and

[0028] FIGS. 7 and 8 are schematically diagrams illustrating the manufacturing processes of the OLED display panel provided by exemplary embodiments of the present disclosure.

DETAILED DESCRIPTION

[0029] Hereinafter, technical solutions of the embodiments will be described in a clearly and fully understandable way in connection with the drawings related to the embodiments of the disclosure. It is apparent that the described embodiments are just a part but not all of the embodiments of the disclosure. Based on the described embodiments herein, a person of ordinary skill in the art can obtain other embodiment(s), without any creative work, which shall be fall within the scope of the disclosure.

[0030] Unless otherwise defined, all the technical and scientific terms used herein have the same meanings as commonly understood by one of ordinary skill in the art to which the present disclosure belongs. The terms, such as “comprise/comprising,” “include/including,” or the like are

intended to specify that the elements or the objects stated before these terms encompass the elements or the objects and equivalents thereof listed after these terms, but not preclude other elements or objects. The terms, “on,” “under,” or the like are only used to indicate relative position relationship, and when the position of the object which is described is changed, the relative position relationship may be changed accordingly.

[0031] In a top-emission OLED device, top electrodes disposed on the light-exiting side must have good light transmittance. The top electrodes in the top emission type OLED device adopt materials, such as thin metal, Indium Tin Oxide (ITO), and indium zinc oxide (IZO). The metal requires thinning treatment due to low transmittance, however, when the metal obtained after the thinning treatment is adopted as electrodes in large area, the resistance is significantly increased, so it is unfavorable in the development of large-size devices. Oxide materials with high transparency, such as ITO and IZO are prepared at low temperature, and the conductivity of the oxide materials is weaker than that of the metals, so the oxide materials cannot be independently used as electrodes.

[0032] In a case of adopting metal as auxiliary electrodes of ITO or IZO, photolithography technology is adopted to form the auxiliary electrodes on a non-light-emitting region of a backboard, so as to reduce the resistance and improve the conductivity of the electrodes. However, the photolithography technology requires complex processes, involves a plurality of mask and exposure processes, and requires high temperature and photoresist erosion process, and the like, the light-emitting layer of an OLED device will be damaged, so this technology is not applicable in a mass-production. Another way is to prepare the auxiliary electrodes on a package cover to improve the conductivity of the electrodes. This way can avoid the problems in the above preparation process. However, as packaging adhesive covers the auxiliary electrodes of the package cover, it is difficult for the auxiliary electrodes run through the adhesive material and contact the top electrodes of the OLED in the pressing process, so the expected effect cannot be obtained.

[0033] More comprehensive description will be given below to the exemplary embodiments of the present disclosure with reference to the accompanying drawings. However, the exemplary embodiments of the present disclosure can be implemented in various forms and shall not be construed as being limited to the examples described herein. These embodiments are provided so that the present disclosure will be more comprehensive and complete, and the concept of the exemplary embodiments is more comprehensively conveyed to a person of skill in the art. The described features, structures or characteristics may be combined in one or more embodiments in any suitable manner. In the following description, numerous details are provided to facilitate the understanding to the embodiments of the present disclosure. However, a person of ordinary skill in the art should appreciate that the technical proposals of the present disclosure may be implemented with one or more of the specific details omitted, or other ways, components, devices, operations and the like may be used. For the purpose of clarity, commonly known technical proposals are not shown or described in detail to avoid obscuring aspects of the embodiments of the present disclosure.

[0034] In addition, the accompanying drawings are only the schematic diagrams of the embodiments of the present

disclosure and not necessarily drawn in proportion. The thickness and the shape of the layers in the accompanying drawings do not reflect the true scale but are only intended to illustrate the embodiments of the present disclosure.

[0035] An exemplary embodiment of the present disclosure provides a package substrate **10**, which is arranged oppositely to an array substrate and used for forming a top-emission type OLED display panel. As illustrated in FIGS. 1-3, the package substrate **10** may comprise: a transparent substrate **101**; a plurality of spacers **102** disposed on the transparent substrate **101**; and auxiliary electrodes **103** disposed on the spacers **102** and in a non-light-emitting region. Orthographic projections of the spacers **102** on the array substrate fall within orthographic areas of a pixel definition layer (PDL) of the array substrate.

[0036] It should be noted that the non-light-emitting region refers to areas except subpixel areas, and the areas correspond to the areas of the PDL in the array substrate.

[0037] For instance, both the position of the spacers **102** and the position of the auxiliary electrodes **103** in the embodiment correspond to the position of the PDL in the array substrate, and only correspond to partial regions of the PDL. The coverage area of the spacers **102** is small, and the coverage area of the auxiliary electrodes **103** is large.

[0038] In the package substrate **10** provided by the exemplary embodiments of the present disclosure, the plurality of spacers **102** are disposed between the transparent substrate **101** and the auxiliary electrodes **103**. The plurality of spacers **102** may provide a stepped structure for the auxiliary electrodes **103**, so that the auxiliary electrodes **103** can be protruded at positions corresponding to the spacers **102**, to allow full contact between the auxiliary electrodes **103** of the package substrate **10** and the top electrodes of the array substrate in the subsequent pressing process, and the resistance of the top electrodes is decreased and the conductivity of the top electrodes is improved.

[0039] Based on the above structure, the material of the auxiliary electrodes **103** may be any one selected from the group consisting of magnesium, silver, aluminum, and ITO. The auxiliary electrodes **103** may contact the top electrodes of the array substrate to reduce the resistance of the top electrodes.

[0040] In the example, as shown in FIGS. 1-3, the transparent substrate **101** may be a base substrate **100** provided with BMs **104**, a CF layer **105** and a planarization layer **106**, and the planarization layer **106** covers a side of the BMs **104** and the CF layer **105** away from the base substrate **100**.

[0041] Orthographic projections of the spacers **102** on the base substrate **100** fall within orthographic areas of the BMs **104** on the base substrate **100**. That is to say, in the direction perpendicular to the base substrate **100**, the projections of the BMs **104** may completely cover the projections of the spacers **102**, and the projection area of the BMs **104** is generally greater than that of the spacers **102**.

[0042] It should be noted that the relative position of the BMs **104** and the CF layer **105** may be varied in the embodiments. For instance, the BMs **104** may be on the lower part (namely close to the base substrate **100**) and the CF layer **105** may be on the upper part (namely close to the planarization layer **106**), or the CF layer **105** may be on the lower part (namely close to the base substrate **100**) and the BMs **104** may be on the upper part (namely close to the planarization layer **106**).

[0043] In addition, for instance, the planarization layer **106** may be formed on the base substrate **100** by spin coating via elastic resin materials, such as phenolic resin, polypropylene resin, polyimide resin and acrylic resin, and covers the BMs **104** and the CF layer **105**, and the thickness of the planarization layer is about 1-2 μm . However, the embodiments of the present disclosure are not limited thereto.

[0044] The transparent substrate **101** in the embodiment may also include other layer structures in addition to the BMs **104**, the CF layer **105** and the planarization layer **106**. Moreover, the transparent substrate **101** in the embodiment may also be only a base substrate **100**, e.g., a glass substrate, or a flexible substrate.

[0045] Optionally, as shown in FIG. 1, the spacers **102** may be post spacers (PS) **1021**; or as shown in FIG. 2, the spacers **102** may be conductive poles **1022**; or as shown in FIG. 3, the spacers **102** may simultaneously include post spacers **1021** and conductive poles **1022** which are directly opposite to each other in position and overlap with each other, and the relative position of the post spacers **1021** and the conductive poles **1022** may be exchanged.

[0046] The post spacers **1021** may be prepared by common photoresist via processes, such as exposure, development and baking. The conductive poles **1022** may be prepared by any one of the conductive materials, such as magnesium, silver, and aluminum.

[0047] For instance, the spacers **102** may be correspondingly disposed in the non-light-emitting region of the package substrate **10**, so as to form a large-area reticular-like structure or columnar-like structure with a height of about 5-10 μm and a diameter of about 15-20 μm .

[0048] It should be noted that one or more subpixels may be arranged between adjacent spacers **102**.

[0049] In an instance that the spacers **102** include the conductive poles **1022**, the conductive poles **1022** shall contact the auxiliary electrodes **103** to maintain the electrical connection, so as to further reduce the resistance of the auxiliary electrodes **103** and improve the conductivity of the auxiliary electrodes.

[0050] As the spacers **102** may provide a stepped structure for the auxiliary electrodes **103**, the spacers may adopt conductive materials or non-conductive materials. However, to further improve the conductivity of the auxiliary electrodes **103**, the embodiment may also adopt the spacers **102** made from conductive materials, for instance, adopt the conductive poles directly, or adopt a multi-layer structure formed by the post spacers and the conductive poles together.

[0051] For example, as shown in FIG. 3, the package substrate **10** in the embodiment of the present disclosure may comprise a base substrate **100**, BMs **104** disposed on the base substrate **100**, a CF layer **105** disposed at gaps on the BMs **104**, a planarization layer **106** disposed on the BMs **104** and the CF layer **105**, conductive poles **1022** disposed on the planarization layer **106**, post spacers **1021** disposed directly above the conductive poles **1022**, and auxiliary electrodes **103** disposed on the post spacers **1021**. For instance, the height of the conductive poles **1022** is about 100-300 nm. For instance, the conductive poles may be silver conductive poles with a height of 300 nm. The height of the post spacers **1021** is about 5-10 μm . For instance, the post spacers may be PS photoresist with a height of 5 μm . The auxiliary electrodes **103**, for instance, may be ITO electrodes with a height about 100 nm. The conductive poles

1022 and the post spacers **1021** together form spacers **102**. Both the spacers **102** and the auxiliary electrodes **103** correspond to areas of a PDL in the array substrate, and the auxiliary electrodes **103** also contact the conductive poles **1022**.

[0052] In this way, the auxiliary electrodes **103** will be protruded at positions corresponding to the spacers **102**, thus realizing the full contact between the auxiliary electrodes **103** of the package substrate **10** and the top electrodes of the array substrate in the subsequent pressing process, and improving the conductivity of the top electrodes.

[0053] An exemplary embodiment of the present disclosure also provides a method of manufacturing a package substrate. A package substrate **10** and an array substrate are oppositely arranged and used for forming a top-emission type OLED display panel. As illustrated in FIG. 4, the method for manufacturing the package substrate may comprise following operations.

[0054] S1: forming a plurality of spacers **102** on a transparent substrate **101**; and

[0055] S2: forming auxiliary electrodes **103** in a non-light-emitting region on the spacers **102**;

[0056] Orthographic projections of the spacers **102** on the array substrate fall within orthographic areas of a PDL in the array substrate.

[0057] It should be noted that the non-light-emitting region refers to areas except subpixel areas, and the areas correspond to the areas of the PDL in the array substrate.

[0058] Detailed description will be given below to the method for manufacturing the package substrate with reference to the accompanying drawings.

[0059] In the step S1, the plurality of spacers **102** are formed on the transparent substrate **101**.

[0060] As shown in FIGS. 1-3, the step S1 may include the following examples:

[0061] forming a plurality of post spacers **1021** on the transparent substrate **101**; or

[0062] forming a plurality of conductive poles **1022** on the transparent substrate **101**;

[0063] or

[0064] forming a plurality of post spacers **1021** on the transparent substrate **101**, and forming a plurality of conductive poles **1022** directly above the post spacers **1021**; or

[0065] forming a plurality of conductive poles **1022** on the transparent substrate **101**, and forming a plurality of post spacers **1021** directly above the conductive poles **1022**.

[0066] For instance, the post spacers **1021** may be prepared by general photoresist materials via processes, such as exposure, development and baking, and the conductive poles **1022** may be prepared by any one of conductive materials, such as magnesium, silver and aluminum.

[0067] In the above embodiments, the spacers **102** may be correspondingly disposed in the non-light-emitting region of the package substrate **10**, so as to form a large-area reticular-like structure or columnar-like structure with a height of about 5-10 μm and a diameter of about 15-20 μm .

[0068] It should be noted that one or more subpixels are arranged between adjacent spacers **102**.

[0069] In the step, the transparent substrate **101** may be a base substrate **100**, e.g., a glass substrate or a flexible substrate; or the transparent substrate **101** may also be a base substrate **100** provided with BMs **104**, a CF layer **105** and a planarization layer **106**. For instance, the transparent

substrate **101** may also comprise other layer structures in addition to the BMs **104**, the CF layer **105** and the planarization layer **106**.

[0070] For the instance that the transparent substrate **101** includes the base substrate **100**, the BMs **104**, the CF layer **105** and the planarization layer **106**, the method for manufacturing the transparent substrate **101** may comprise following operations.

[0071] forming the BMs **104** and the CF layer **105** on the base substrate **100**; and

[0072] forming the planarization layer **106** on the BMs **104** and the CF layer **105**.

[0073] In an embodiment, the above step, for instance, may include: firstly, forming the BMs **104** on the base substrate **100** by exposure, development, and the like; secondly, forming the CF layer **105** at gaps on the BMs **104** via exposure, development and the like; then, forming the planarization layer **106** on the BMs **104** and the CF layer **105** by exposure, development, etching, and the like.

[0074] In another embodiment, the above step, for instance, may include: firstly, forming the CF layer **105** on the base substrate **100** by exposure, development, and the like; secondly, forming the BMs **104** at gaps on the CF layer **105** via exposure, development and the like; then, forming the planarization layer **106** on the BMs **104** and the CF layer **105** by exposure, development, etching, and the like.

[0075] It should be noted that in a case that the transparent substrate **101** comprises the BMs **104**, orthographic projections of the spacers **102** on the base substrate **100** fall within orthographic areas of the BMs **104** on the base substrate **100**, namely the BMs **104** can completely shield the spacers **102**.

[0076] In the step S2, the auxiliary electrodes **103** are formed in the non-light-emitting region on the spacers **102**.

[0077] In a case that the spacers **102** include the conductive poles **1022**, the auxiliary electrodes **103** contact the conductive poles **1022**, so as to reduce the resistance of the auxiliary electrodes **103** and improve the conductivity of the auxiliary electrodes **103**.

[0078] In the step, the material of the auxiliary electrodes **103** may be any one selected from the group consisting of magnesium, silver, aluminum and ITO, but the embodiment of the present disclosure is not limited thereto. The method for preparing the auxiliary electrodes **103**, for instance, may include: firstly, forming a conductive layer with a thickness of about 10-100 nm on the spacers **102** by a physical vapor deposition (PVD) process, or an evaporation process; secondly, performing processes, such as exposure, development and etching on the conductive layer via a mask and obtaining a required pattern of the auxiliary electrodes **103**.

[0079] The exemplary embodiment also provides an OLED display panel. As illustrated in FIG. 5, the display panel comprises the foregoing package substrate **10**, an array substrate **20**, and sealant **30** and filling adhesive **40** disposed between the package substrate and the array substrate.

[0080] Top electrodes **201** of the array substrate **20** contact the auxiliary electrodes **103** of the package substrate **10**. The sealant **30** is disposed in a peripheral region, namely the non-display region, of the package substrate **10**. The filling adhesive **40** is filled into gaps between the package substrate **10** and the array substrate **20**.

[0081] It should be noted that the filling adhesive **40** adopted in the embodiment has thermal expansibility, will fill the gaps between the package substrate **10** and the array substrate **20** after being heated, and is not subjected to

thermal expansion before being heated, so the thickness of the filling adhesive is designed to be less than the thickness of the sealant 30.

[0082] As the top electrodes 201 of the array substrate 20 and the auxiliary electrodes 103 of the package substrate 10 have full contact each other before the filling adhesive 40 being heated, the case of insufficient contact between the top electrodes 201 and the auxiliary electrodes 103 introduced by the filling adhesive 40 can be effectively avoided. In addition, the height of the auxiliary electrodes 103 of the package substrate 10 at positions corresponding to the spacers 102 is large; the height of the top electrodes 201 of the array substrate 20 at positions corresponding to the PDL 202 is large; and the positions of the spacers 102 also correspond to the PDL 202, so the auxiliary electrodes 103 and the top electrodes 201 can contact each other more easily in the substrate pressing process.

[0083] In the exemplary embodiment of the present disclosure, the filling adhesive 40 may include first filling adhesive 401 close to a side of the package substrate 10 and second filling adhesive 402 close to a side of the array substrate 20 facing the side of the package substrate 10.

[0084] The first filling adhesive 401 may include thermal expansion material; the second filling adhesive 402 may include UV curing material; and the first filling adhesive 401 and the second filling adhesive 402 have different viscosities.

[0085] In this way, as the first filling adhesive 401 and the second filling adhesive 402 have different viscosities, the filling adhesive mixing phenomenon in the pressing process can be effectively reduced; and as the second filling adhesive 402 covers the surface of the first filling adhesive 401, the pollution, caused by an expansion agent in the first filling adhesive 401 contacts the OLED device, can be avoided.

[0086] Optionally, the composition of the first filling adhesive 401 may include a mixture of thermal expansion agent and resin material, and the volume ratio of the thermal expansion agent to the resin material is less than 1:2. The thermal expansion agent may be expanded under the condition of about 25-100°C, which may be a transparent material. For instance, it may include a mixture formed by alkali silicate and polyol, an oxide-molybdenum gradient material, and the like. The resin may be cured under the condition of UV irradiation. For instance, the resin may include homopolymer or copolymer of monomers, such as epoxy resin, glycidyl acrylate, glycidyl methacrylate (GMA), methyl methacrylate (MMA), ethyl methacrylate, n-butyl methacrylate, methyl polyacrylic acid 6,7 heptane, and 2-hydroxyethyl methacrylate; melamine resin, unsaturated polyester resin, silicone resin, furan resin, or the like. The viscosity of the first filling adhesive 401 may be about 500-2,000 mPa·s. The first filling adhesive may be filled into regions encircled by the spacers 102 of the package substrate 10 by printing, and the filling height is about 1-5 μm.

[0087] Optionally, the composition of the second filling adhesive 402 may include UV curing resin materials, such as homopolymer or copolymer of monomers, such as epoxy resin, glycidyl acrylate, glycidyl methacrylate (GMA), methyl methacrylate (MMA), ethyl methacrylate, n-butyl methacrylate, methyl polyacrylic acid 6,7 heptane, and 2-hydroxyethyl methacrylate; melamine resin, unsaturated polyester resin, silicone resin, furan resin, or the like. The viscosity of the second filling adhesive 402 may be about 10-100 mPa·s. The second filling adhesive 402 may be filled

into the regions encircled by the spacers 102 of the package substrate 10 by printing and cover the first filling adhesive 401, and the filling height is about 1-5 μm.

[0088] Optionally, the composition of the sealant 30 may include UV curing resin materials, such as homopolymer or copolymer of monomers, such as epoxy resin, glycidyl acrylate, glycidyl methacrylate (GMA), methyl methacrylate (MMA), ethyl methacrylate, n-butyl methacrylate, methyl polyacrylic acid 6,7 heptane, and 2-hydroxyethyl methacrylate; melamine resin, unsaturated polyester resin, silicone resin, furan resin, or the like. The viscosity of the sealant 30 is about 10,000-400,000 mPa·s, and the thickness after curing is about 10-25 μm.

[0089] The embodiments of the present disclosure also provide a method for manufacturing an OLED display panel. As illustrated in FIG. 6, the manufacturing method comprises following operations.

[0090] S10: providing a package substrate 10 and an array substrate 20;

[0091] S20: as shown in FIG. 7, coating sealant 30 on a peripheral region of the package substrate 10, coating filling adhesive 40 on regions, among the plurality of spacers 102 in the sealant 30, on the auxiliary electrodes 103 of the package substrate 10, and allowing the filling adhesive 40 has a height to be less than that of the sealant 30;

[0092] S30: as shown in FIG. 8, pressing the package substrate 10 and the array substrate 20, and allowing the top electrodes 201 of the array substrate to contact the auxiliary electrodes 103 of the package substrate 10; and

[0093] S40: as shown in FIG. 5, heating the package substrate 10, and allowing the filling adhesive 40 to fill gaps between the package substrate 10 and the array substrate 20.

[0094] The filling adhesive 40 may include first filling adhesive 401 close to a side of the package substrate 10 and second filling adhesive 402 close to a side of the array substrate 20 facing the side of the package substrate 10. The first filling adhesive 401 may include thermal expansion materials; the second filling adhesive 402 may include UV curing materials; and the first filling adhesive 401 and the second filling adhesive 402 have different viscosities.

[0095] The step S40, for instance, may include: heating the package substrate 10, allowing the first filling adhesive 402 close to the side of the package substrate 10 to be expanded, and pushing the second filling adhesive 402 close to the side of the array substrate 20 to fill all the gaps between the package substrate 10 and the array substrate 20.

[0096] For instance, as shown in FIG. 6, the method for manufacturing the OLED display panel may also comprise:

[0097] S50: curing the sealant 30 by UV irradiation to finish the packaging of the OLED display panel.

[0098] For instance, the method for manufacturing the OLED display panel in the embodiment may comprise the following operations: coating sealant 30 on a peripheral region of the package substrate 10; printing about 2 μm composite materials of zirconia-molybdenum gradient materials and epoxy resins (namely the first filling adhesive 401) and about 2 μm second filling adhesive 402 in sequence on the regions among the spacers 102, on the auxiliary electrodes 103; and allowing the overall height of the first filling adhesive 401 and the second filling adhesive 402 not to exceed the height of the sealant 30; pressing the package substrate 10 and the array substrate 20, and allowing the auxiliary electrodes 103 of the package substrate 10 to contact the top electrodes 201 of the array substrate 20;

heating the package substrate **10**, allowing the first filling adhesive **401** to be expanded, and pushing the second filling adhesive **402** to fill the inner space between the two substrates; and curing the sealant **30** by UV irradiation, and finishing the packaging of the OLED display panel.

[0099] In the OLED display panel provided by the exemplary embodiment of the present disclosure, the filling adhesive **40** may expose the auxiliary electrodes **103** of the package substrate **10**, so that the auxiliary electrodes **103** of the package substrate **10** can contact the top electrodes **201** of the array substrate **20** at first in the process of pressing the package substrate **10** and the array substrate **20**; subsequently, the first filling adhesive **401** is controlled to be heated and expanded to push the second filling adhesive **402** with low viscosity to diffuse, so that the adhesive fills the entire gap space between the package substrate **10** and the array substrate **20**; then, the sealant **30** and the filling adhesive **40** are subjected to UV curing, to allow full contact between the auxiliary electrodes **103** and the top electrodes **201** and the sufficient filling of the adhesive.

[0100] It should be noted that the details of the method for manufacturing the OLED display panel have been described in corresponding OLED display panel, so no further description will be repeated herein.

[0101] The exemplary embodiments of the present disclosure also provide an OLED display device, which comprises the foregoing OLED display panel. In the OLED display device, the auxiliary electrodes **103** of the package substrate **10** and the top electrodes **201** of the array substrate **20** can maintain good contact, so as to reduce the resistance of the top electrodes **201** and improve the conductivity of the top electrodes.

[0102] In the exemplary embodiments of the present disclosure, the OLED display device, for instance, may comprise any product or component with display function, such as a mobile phone, a tablet PC, a TV, a notebook computer, a digital picture frame and a navigator, but the embodiments of the present disclosure are not limited thereto.

[0103] The foregoing is only the exemplary embodiments of the present disclosure, but the scope of the present disclosure is not limited thereto. A person of ordinary skill in the art can make various changes and modifications without departing from the spirit of the present disclosure, and such changes and modifications shall fall into the scope of the present disclosure.

What is claimed is:

1. A package substrate, arranged oppositely to an array substrate, comprising:

a transparent substrate;

a plurality of spacers provided on the transparent substrate; and

auxiliary electrodes provided on the spacers and in a non-light-emitting region;

wherein orthographic projections of the plurality of spacers on the array substrate fall within orthographic areas of a pixel define layer (PDL) on the array substrate.

2. The package substrate according to claim 1, wherein the plurality of spacers are post spacers; or the plurality of spacers are conductive poles.

3. The package substrate according to claim 1, wherein the spacers include post spacers and conductive poles which are directly opposite to each other in position and overlap with each other.

4. The package substrate according to claim 2, wherein material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and indium tin oxide (ITO); and material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

5. The package substrate according to claim 1, wherein the transparent substrate is a base substrate provided with black matrixes (BMs), a color filter (CF) layer and a planarization layer;

the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and

orthographic projections of the spacers on the base substrate fall within orthographic projections of the BMs on the base substrate.

6. The package substrate according to claim 3, wherein the material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and ITO; and the material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

7. The package substrate according to claim 6, wherein the transparent substrate is a base substrate provided with BMs, a CF layer and a planarization layer;

the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and

orthographic projections of the spacers on the base substrate fall within orthographic projections of the BMs on the base substrate.

8. A method for manufacturing the package substrate according to claim 1, wherein the package substrate and the array substrate are oppositely arranged; and the method comprises:

forming a plurality of spacers on the transparent substrate; and

forming the auxiliary electrodes in a non-light-emitting region on the spacers, wherein orthographic projections of the spacers on the array substrate fall within orthographic areas of the PDL on the array substrate.

9. The method according to claim 8, further comprising: forming post spacers on the transparent substrate; or forming conductive poles on the transparent substrate.

10. The method according to claim 8, further comprising: forming post spacers and conductive poles, which are directly opposite to and overlap with each other, on the transparent substrate.

11. The method according to claim 8, wherein the material of the auxiliary electrodes is any one selected from the group consisting of magnesium, silver, aluminum and Indium Tin Oxide (ITO); and the material of the conductive poles is any one selected from the group consisting of magnesium, silver and aluminum.

12. The method according to claim 8, wherein the transparent substrate is a base substrate provided with BMs, a CF layer and a planarization layer;

the planarization layer covers a side of the BMs and the CF layer away from the base substrate; and

orthographic projections of the spacers on the base substrate fall within orthographic areas of the BMs on the base substrate.

13. An organic light-emitting diode (OLED) display panel, comprising the package substrate according to claim 1, an array substrate, and sealant and filling adhesive between the package substrate and the array substrate,

wherein top electrodes of the array substrate contact the auxiliary electrodes of the package substrate; and the filling adhesive is filled into gaps between the package substrate and the array substrate.

14. The display panel according to claim **13**, wherein the filling adhesive includes first filling adhesive close to a side of the package substrate and second filling adhesive close to a side of the array substrate facing the side of the package substrate; and

the first filling adhesive includes thermal expansion materials; the second filling adhesive includes UV curing materials; and the first filling adhesive and the second filling adhesive have different viscosities.

15. A method for manufacturing an OLED display panel, comprising:

providing the package substrate according to claim **1** and an array substrate;

applying sealant on the periphery of the package substrate, applying filling adhesive on regions, among the plurality of spacers in the sealant, on the auxiliary

electrodes of the package substrate, and allowing the height of the filling adhesive to be less than the height of the sealant;

pressing the package substrate and the array substrate, to allow top electrodes of the array substrate to contact the auxiliary electrodes of the package substrate; and

heating the package substrate, to allow filling adhesive to fill into gaps between the package substrate and the array substrate.

16. The manufacturing method according to claim **15**, wherein the heating of the package substrate to allow the filling adhesive to fill into the gaps between the package substrate and the array substrate comprises:

heating the package substrate, allowing the first filling adhesive close to a side of the package substrate to be expanded, and pushing the second filling adhesive close to a side of the array substrate to fill the gaps between the package substrate and the array substrate.

* * * * *

专利名称(译)	封装基板，其制造方法，OLED显示面板及其制造方法		
公开(公告)号	US20190058153A1	公开(公告)日	2019-02-21
申请号	US15/974903	申请日	2018-05-09
[标]申请(专利权)人(译)	京东方科技集团股份有限公司		
申请(专利权)人(译)	京东方科技集团股份有限公司		
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发明人	LUO, CHENGYUAN		
IPC分类号	H01L51/52 H01L27/32 H01L51/56		
CPC分类号	H01L51/5246 H01L27/3246 H01L51/5203 H01L51/56 H01L27/322 H01L2251/5315 H01L51/5212 H01L51/5228 H01L51/524 H01L51/525 H01L51/0024		
优先权	201710701692.6 2017-08-16 CN		
外部链接	Espacenet USPTO		

摘要(译)

提供一种封装基板,其制造方法,有机发光二极管(OLED)显示面板及其制造方法。封装基板包括透明基板;多个间隔物设置在透明基板上;设置在隔离物上和非发光区域中的辅助电极和辅助电极。阵列基板上的间隔物的正投影落在阵列基板上的像素限定层(PDL)的正交区域内。

